rfmd.com

# **RF2314**

### **GENERAL PURPOSE LOW NOISE AMPLIFIER**

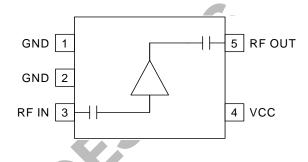
**RoHS Compliant & Pb-Free Product** Package Style: SOT 5-Lead

#### **Features**

- 150 MHz to 2500 MHz Operation
- 2.7 V to 6.0 V Single Supply
- +18dBm Output IP3 at 5V
- 14dB Gain at 900MHz
- 8.6dB Gain at 1900MHz
- Low Current Consumption of 5mA at 3V

### **Applications**

- Broadband Gain Blocks
- Final PA for Low-Power Applications
- IF or RF Buffer Amplifiers
- Driver Stage for Power Amplifiers
- Oscillator Loop Amplifiers



Functional Block Diagram

# **Product Description**

The RF2314 is a general purpose, low-cost, high performance amplifier designed for operation from a 2.7V to 6V supply with low current consumption. The circuit configuration with resistive feedback allows for broadband cascadable amplification. Feedback with capacitive compensation extends the bandwidth of the amplifier, and is designed for optimized noise figure. The device is unconditionally stable and internally matched to  $50\Omega$ . No external components are required. The RF2314 is available in a very small industry-standard SOT 5-lead surface mount package, enabling compact designs which conserve board space.

### **Ordering Information**

RF2314 General Purpose Low Noise Amplifier RF2314PCBA-41X Fully Assembled Evaluation Board

### Optimum Technology Matching® Applied

	•		
<b>☑</b> GaAs HBT	☐ SiGe BiCMOS	☐ GaAs pHEMT	☐ GaN HEMT
☐ GaAs MESFET	☐ Si BiCMOS	☐ Si CMOS	☐ RF MEMS
☐ InGaP HBT	☐ SiGe HBT	☐ Si BJT	

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# **RF2314**



### **Absolute Maximum Ratings**

Parameter	Rating	Unit
Supply Voltage	8.0	V
Supply Current	32	mA
Storage Temperature	-40 to +150	°C



#### Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EUDirective 2002/95/EC (at time of this document revision).

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Parameter	Specification			Unit	Condition		
i arameter	Min.	Тур.	Max.	UIIIL	Condition		
Operating Range							
Overall Frequency Range	150		2500	MHz			
Supply Voltage	2.7		6.0	V			
Operating Current (I <sub>CC</sub> )	2	5.7	9	mA	V <sub>CC</sub> =3V, Temp=27°C		
	9	12.5	16	mA	V <sub>CC</sub> =5V, Temp=27°C		
Operating Ambient Temperature	-40		+85	С			
3.0V Performance							
Gain		16.6		dB	Freq=150MHz, V <sub>CC</sub> =3V, Temp=27 °C		
Gain	11	12.9	14	dB	Freq=900MHz, V <sub>CC</sub> =3V, Temp=27°C		
Noise Figure		1.4		dB			
OIP3	+3	+9		dBm			
OP1dB	-4	-1	+1	dBm			
Input Return Loss		10		dB			
Output Return Loss		17		dB			
Isolation		20		dB			
Gain	6.5	7.9	9	dB	Freq=1900MHz, V <sub>CC</sub> =3V, Temp=27°C		
OIP3	+9	+12.5		dBm			
OP1dB	-2	-0.5	+1	dBm			
Gain	4	5.2	7	dB	Freq=2400MHz, V <sub>CC</sub> =3V, Temp=27°C		
OIP3	+11	+15.3		dBm			
OP1dB	-1	+1.1	+3	dBm			



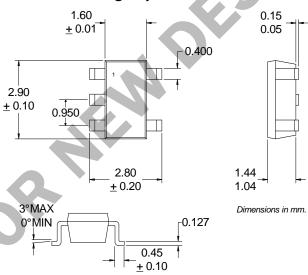
Dovomotov		Specification			Condition	
Parameter	Min.	Тур.	Max.	Unit	Condition	
5.0V Performance						
Gain		19.1		dB	Freq=150MHz, V <sub>CC</sub> =5V, Temp=27 °C	
Gain	12	14.2	16	dB	Freq=900 MHz, V <sub>CC</sub> =5 V, Temp=27 °C	
Noise Figure		1.5		dB		
OIP3	+14	+18		dBm		
OP1dB	+3	+8	+11	dBm		
Input Return Loss		13		dB		
Output Return Loss		28		dB	350	
Isolation		20		dB		
Gain	6	8.2	10	dB	Freq=1900MHz, V <sub>CC</sub> =5V, Temp=27°C	
OIP3	+18	+22		dBm		
OP1dB	+5	+6.7	+9	dBm		
Gain	3.5	5.1	7	dB	Freq=2400 MHz, V <sub>CC</sub> =5V, Temp=27°C	
OIP3	+19	+23		dB		
OP1dB	+6	+7.9	+10	dB		



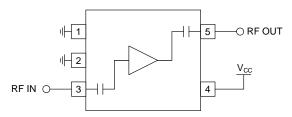
Pin	Function	Description	Interface Schematic		
1	GND	Ground connection. For best performance, keep traces physically short and connect immediately to ground plane.			
2	GND	Same as pin 1.			
3	RF IN	RF input pin. This pin is internally DC-blocked and thus does not require an external blocking capacitor. The input impedance of this pin is internally matched to $50\Omega$ using resistive feedback.	VCC \$300Ω RF IN O—I—O RF OUT		
4	VCC	Supply connection. Generally, there is no need for an external bypass capacitor.	See pin 3 schematic.		
5	RF OUT	RF output pin. The output impedance of this pin is internally matched to $50\Omega$ using resistive feedback.	See pin 3 schematic.		

# Package Drawing

## Package Style: SOT 5-Lead

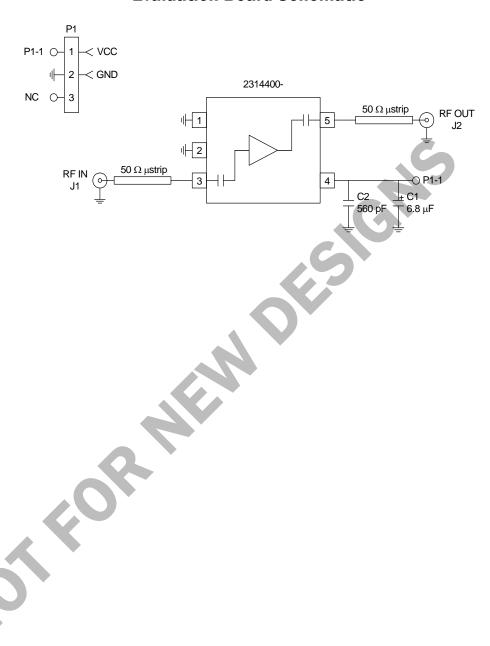


# **Application Schematic**





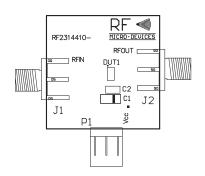
# **Evaluation Board Schematic**

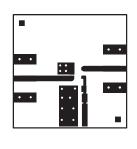




# Evaluation Board Layout Board Size 1.0" x 1.0"

Board Thickness 0.031", Board Material FR-4

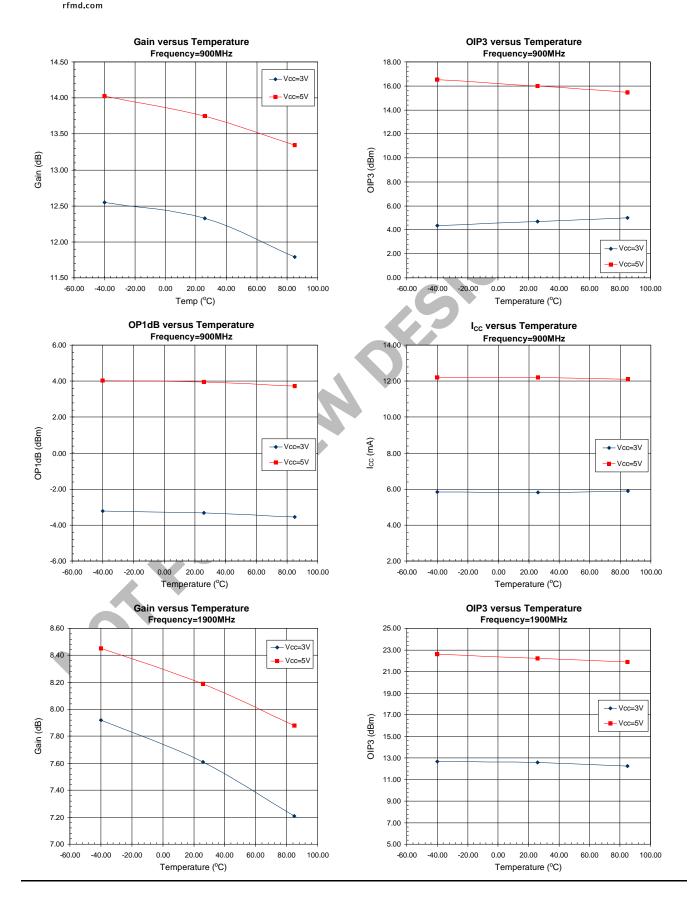






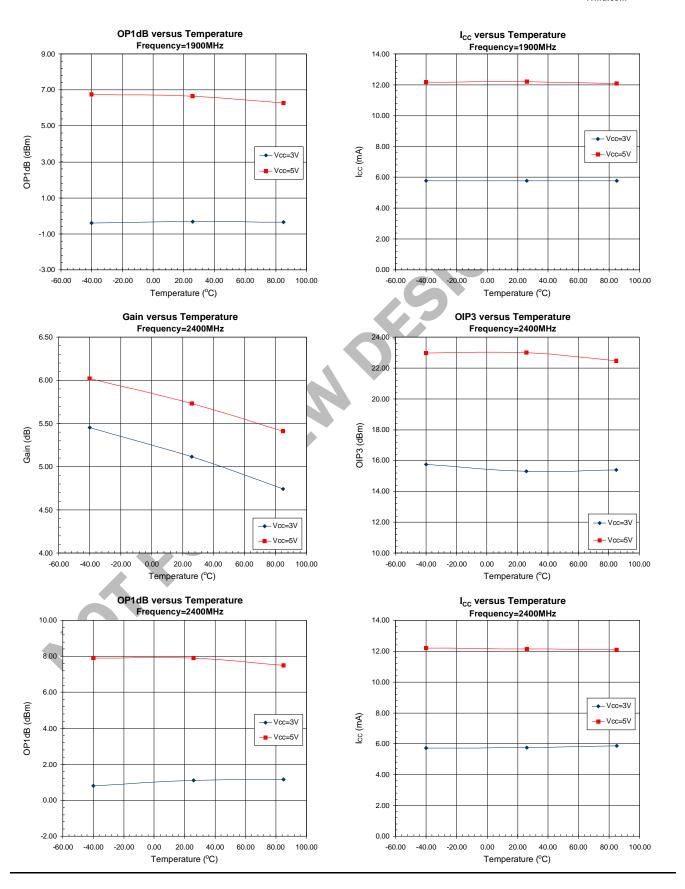




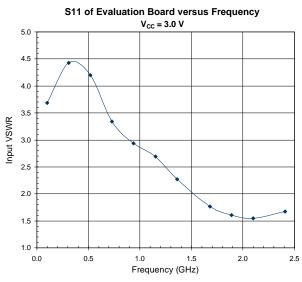


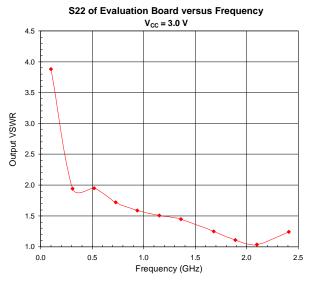
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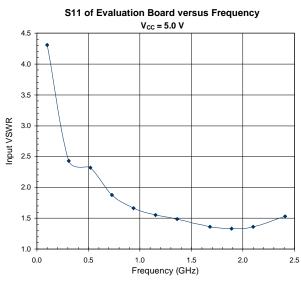


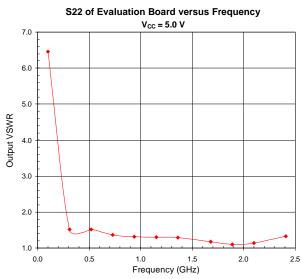


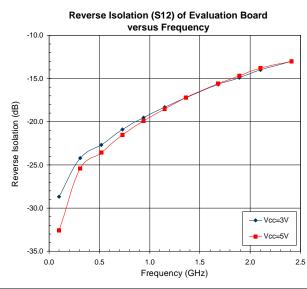






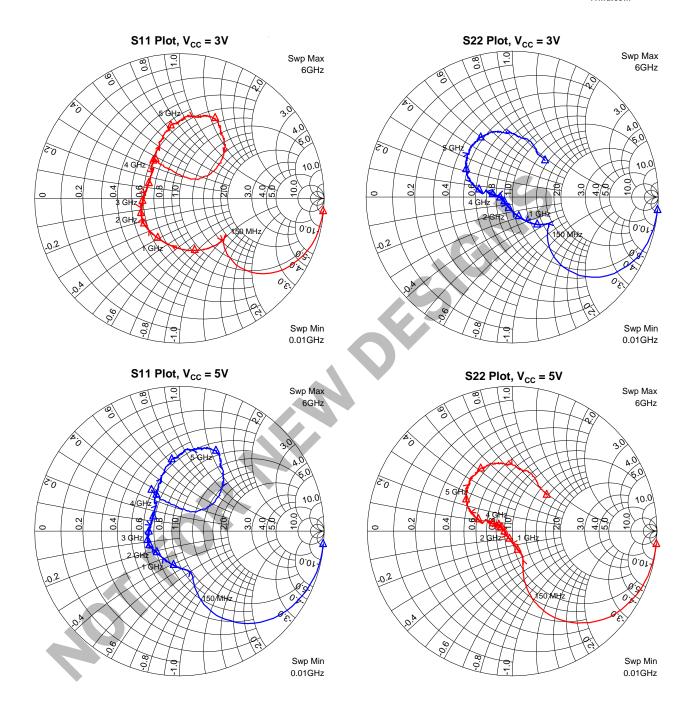






# **RF2314**







## **PCB Design Requirements**

#### **PCB Surface Finish**

The PCB surface finish used for RFMD's qualification process is Electroless Nickel, immersion Gold. Typical thickness is  $3\mu$ inch to  $8\mu$ inch Gold over  $180\mu$ inch Nickel.

#### **PCB Land Pattern Recommendation**

PCB land patterns are based on IPC-SM-782 standards when possible. The pad pattern shown has been developed and tested for optimized assembly at RFMD; however, it may require some modifications to address company specific assembly processes. The PCB land pattern has been developed to accommodate lead and package tolerances.

#### **PCB Metal Land Pattern**

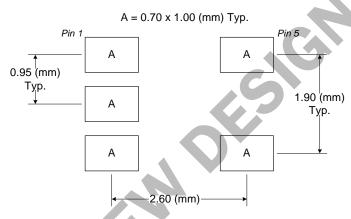


Figure 1. PCB Metal Land Pattern (Top View)

#### **PCB Solder Mask Pattern**

Liquid Photo-Imageable (LPI) solder mask is recommended. The solder mask footprint will match what is shown for the PCB metal land pattern with a 3mil expansion to accommodate solder mask registration clearance around all pads. The center-grounding pad shall also have a solder mask clearance. Expansion of the pads to create solder mask clearance can be provided in the master data or requested from the PCB fabrication supplier.

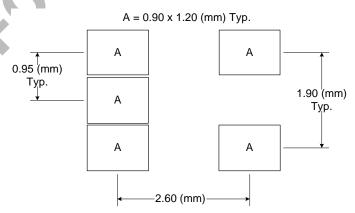


Figure 2. PCB Solder Mask Pattern (Top View)



### **RoHS\* Banned Material Content**

RoHS Compliant: Yes
Package total weight in grams (g): 0.014
Compliance Date Code: 0521
Bill of Materials Revision: Pb Free Category: e3

Bill of Materials	Parts Per Million (PPM)						
	Pb	Cd	Hg	Cr VI	PBB	PBDE	
Die	0	0	0	0	0	0	
Molding Compound	0	0	0	0	0	0	
Lead Frame	0	0	0	0	0	0	
Die Attach Epoxy	0	0	0	0	0	0	
Wire	0	0	0	0	0	0	
Solder Plating	0	0	0	0	0	0	

This RoHS banned material content declaration was prepared solely on information, including analytical data, provided to RFMD by its suppliers, and applies to the Bill of Materials (BOM) revision noted

Please contact
RFMD Technical Support
at (336) 678-5570
for more information.

<sup>\*</sup> DIRECTIVE 2002/95/EC OF THE EUROPEAN PARLIAMENT AND OF THE COUNCIL of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment